## Electronic Supplemental Information for

## Hydrogen Plasma–Treated MoSe<sub>2</sub> Nanosheets Enhance the Efficiency and Stability of Organic Photovoltaics

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Fig. S1.  $J-V^2$  characteristics of devices, allowing calculations of the (a) hole and

(b) electron mobilities using the Mott–Gurney equation.



Fig. S2. AFM topographic images (5 × 5 μm) of blend films: (a) PTB7-TH:

PC<sub>71</sub>BM:10%MoSe<sub>2</sub>, (b) PTB7-TH:PC<sub>71</sub>BM:20%MoSe<sub>2</sub>.



Fig. S3. Corresponding 1D GIWAXS profiles reduced from the (a) in-plane and

(b) out-plane directions.



Fig. S4. Powder X-ray diffraction pattern of the films.



Fig. S5. TEM images of active layers incorporating (a) MoSe<sub>2</sub> and (b) hydrogen

plasma-treated MoSe<sub>2</sub>.



Fig. S6. J–V characteristics incorporating MoSe<sub>2</sub> prepared with different concentration.

Active layer <sup>a</sup>	V <sub>oc</sub> (V)	J <sub>SC</sub> (mA cm <sup>-2</sup> )	FF(%)	PCE <sub>max</sub> (%)
PTB7-TH:PC <sub>71</sub> BM:10% MoSe <sub>2</sub>	$0.78 \pm 0.01$	$17.23 \pm 0.2$	$0.7 \pm 0.2$	9.32
PTB7-TH :TH:PC <sub>71</sub> BM:20% MoSe <sub>2</sub>	$0.78 \pm 0.01$	$17.6 \pm 0.3$	$0.67 \pm 0.3$	9.26
a) Weight ratio of D:A = 1:1.5 Twenty devices were fabricated.				

Table S1 Different concentration of ternary blends devices' photovoltaic

performances.



Fig. S7. SEM image of MoSe<sub>2</sub>.



Fig. S8. Schematic representation of the chemical structures of (a) PBDTTBO,

and (b) IT-4F.